Laser-Induced Microexplosions: creating stellar conditions on an optical bench

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microstructuring of transparent materials

microstructuring of transparent materials

laser surgery

microstructuring of transparent materials

laser surgery

electronic and structural transitions

microstructuring of transparent materials

laser surgery

electronic and structural transitions

laser assisted chemistry



5 mm

1

a data sa at



focus laser beam inside material...



high intensity at focus...



... causes nonlinear ionization...



and microscopic bulk damage



laser field ionization



laser field ionization



avalanche ionization



avalanche ionization



Damage mechanisms:

- explosive
- thermal
- defect forming

Applications:

data storage

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data storage



Applications:

- data storage
- photonic devices

Applications:

- data storage
- photonic devices
- internal micromachining

Outline

Damage morphology

- Energy deposition
- **Dynamics**











more energy

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Electron Microscopy:

explosive damage forms voids

100 fs, 500 nJ 0.65 NA fused silica

summary of damage mechanisms

single shot	multiple shot (25 MHz)
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low energy

high energy

summary of damage mechanisms

	single shot	multiple shot (25 MHz)
low energy		
high energy	explosive	

summary of damage mechanisms

	single shot	multiple shot (25 MHz)
low energy		thermal
high energy	explosive	

summary of damage mechanisms

	single shot	multiple shot (25 MHz)
low energy	?	thermal
high energy	explosive	

Outline

Damage morphology

Energy deposition

Dynamics
Determine threshold for damage:

- Optical microscopy
- Transmission
- Dark field scattering

optical microscopy



optical microscopy



6.6 nJ

transmission of pump beam in fused silica



Dark-field scattering



block probe beam...



...bring in pump beam...



...damage scatters probe beam





vary numerical aperture in Corning 0211





fit gives threshold intensity: $I_{th} = 2.5 \times 10^{17} \text{ W/m}^2$





vary material...



threshold increases with bandgap...



...but not very much



same trend at 400 nm



Outline

Damage morphology

Energy deposition

Dynamics

















sapphire

3 µJ pulse

3.8 ns delay

40 µm radius



water ("self-healing")

1.0 µJ pulse

35 ns delay

58 µm radius



















time-resolved scattering setup



signal proportional to area of scatterer






- submicron-scale bulk micromachining
- weak bandgap and wavelength dependence
- only a few nanojoules required

5-nJ threshold: unamplified micromachining



5-nJ threshold: unamplified micromachining



waveguide machining



waveguide machining



Photonic devices

- Photonic devices
- Wavelength-selective splitter









- Photonic devices
- Wavelength-selective splitter
- Photonic bandgap materials



- Propagation of pulses
- Mechanisms

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For a copy of this talk and additional information, see:

http://mazur-www.harvard.edu